Low-ohmic four-pole double-throw analog switch

Rev. 1 — 20 January 2014

Product data sheet

1. General description

The NX3DV2567-Q100 is a four-pole double-throw analog switch (4PDT) optimized for switching WLAN-SIM supply, data and control signals. It has one digital select input (S) and four switches each with two independent input/outputs (nY0 and nY1) and a common input/output (nZ). Schmitt-trigger action at S, makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 1.4 V to 4.3 V.

Lower-level logic signals can drive pin S without a significant increase in supply current I_{CC} , due to a low input voltage threshold. This characteristic makes it possible for the NX3DV2567-Q100 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3DV2567-Q100 allows signals with amplitude up to V_{CC} to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance for supply path:
 - 0.5 Ω (typical) at V_{CC} = 1.8 V
 - 0.45 Ω (typical) at V_{CC} = 2.7 V
- Low ON resistance for data path:
 - 7 Ω (typical) at V_{CC} = 1.8 V
 - 6 Ω (typical) at V_{CC} = 2.7 V
- Low ON capacitance for data path
- Wide –3 dB bandwidth > 160 MHz
- Break-before-make switching
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A exceeds 4000 V
 - HBM JESD22-A114F Class 3A exceeds 4000 V
 - MIL-STD-883, method 3015 Class 3A I/O to GND exceeds 7000 V
 - ◆ HBM JESD22-A114F Class 3A I/O to GND exceeds 7000 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption



Low-ohmic four-pole double-throw analog switch

- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply for supply path switch)

3. Applications

- Cell phone, PDA, digital camera, printer and notebook
- LCD monitor, TV and set-top box

4. Ordering information

Table 1. Ordering information

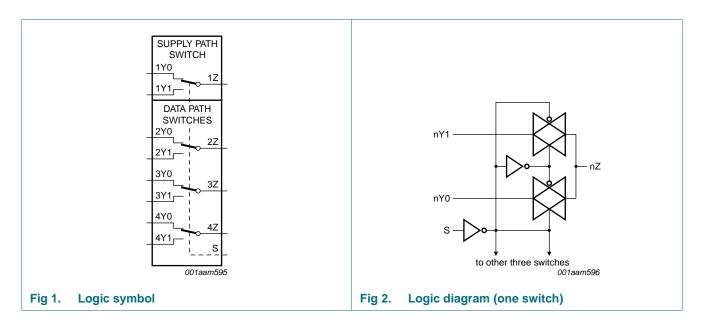
| Type number | Package | | | |
|------------------|-------------------|----------|--|-----------|
| | Temperature range | Name | Description | Version |
| NX3DV2567HR-Q100 | –40 °C to +125 °C | HXQFN16U | plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; UTLP based; body 3 x 3 x 0.5 mm | SOT1039-1 |

5. Marking

Table 2. Marking codes

| Type number | Marking code |
|------------------|--------------|
| NX3DV2567HR-Q100 | D60 |

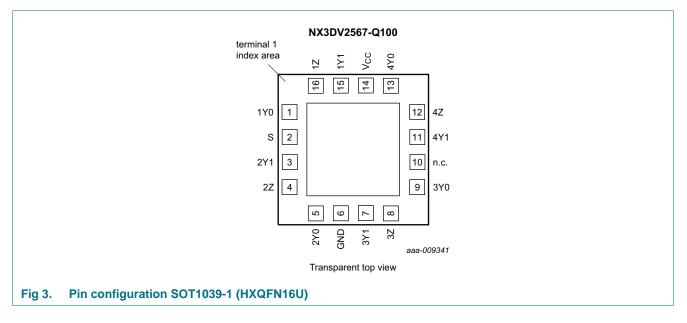
6. Functional diagram



Low-ohmic four-pole double-throw analog switch

7. Pinning information

7.1 Pinning



7.2 Pin description

| Table 3. | Pin | description |
|----------|-----|-------------|
| | | |

| Symbol | Pin | Description |
|-----------------|----------|---|
| 1Y0 | 1 | independent input or output (supply switch) |
| 2Y0, 3Y0, 4Y0 | 5, 9, 13 | independent input or output (data switch) |
| S | 2 | select input |
| 1Y1 | 15 | independent input or output (supply switch) |
| 2Y1, 3Y1, 4Y1 | 3, 7, 11 | independent input or output (data switch) |
| 1Z | 16 | common output or input (supply switch) |
| 2Z, 3Z, 4Z | 4, 8, 12 | common output or input (data switch) |
| GND | 6 | ground (0 V) |
| n.c. | 10 | not connected |
| V _{CC} | 14 | supply voltage |

8. Functional description

Table 4.Function table^[1]

| Input S | Channel on |
|---------|------------|
| L | nY0 |
| Н | nY1 |

[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic four-pole double-throw analog switch

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|-----------------|----------------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| VI | input voltage | select input S | <u>[1]</u> –0.5 | +4.6 | V |
| V _{SW} | switch voltage | | 2 -0.5 | $V_{CC} + 0.5$ | V |
| I _{IK} | input clamping current | V _I < -0.5 V | -50 | - | mA |
| I _{SK} | switch clamping current | $V_{I} < -0.5$ V or $V_{I} > V_{CC}$ + 0.5 V | - | ±50 | mA |
| I _{SW} | switch current | supply path switch | | | |
| | | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | - | ±350 | mA |
| | | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current | - | ±500 | mA |
| | | data path switch | | | |
| | | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | - | ±128 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ | [3] _ | 250 | mW |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] Above 135 °C, the value of P_{tot} derates linearly with 16.9 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------|-------------------------------------|---------------------------|--------------|-----------------|------|
| V _{CC} | supply voltage | | 1.4 | 4.3 | V |
| VI | input voltage | select input S | 0 | 4.3 | V |
| V _{SW} | switch voltage | | <u>[1]</u> 0 | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | V_{CC} = 1.4 V to 4.3 V | [2] _ | 200 | ns/V |

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current flows from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

Low-ohmic four-pole double-throw analog switch

11. Static characteristics

Table 7. Static characteristics

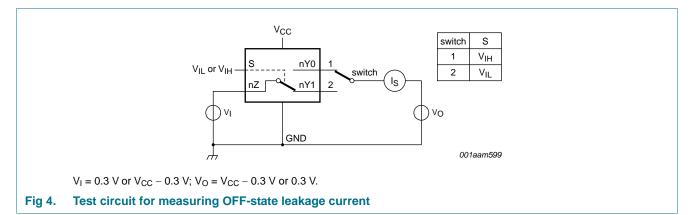
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

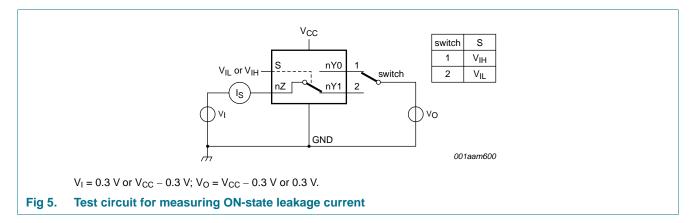
| Symbol | Parameter | Conditions | Ta | _{mb} = 25 | °C | T _{amb} = | –40 °C to | +125 °C | Uni |
|---------------------|--------------------------------|---|-----|--------------------|------|--------------------|----------------|-----------------|---------|
| | | | Min | Тур | Max | Min | Мах (85 °С) | Max (125 °C) | |
| ViH | HIGH-level | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | 0.9 | - | - | 0.9 | - | - | V |
| | input voltage | $V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$ | 0.9 | - | - | 0.9 | - | - | V |
| | | V_{CC} = 2.3 V to 2.7 V | 1.1 | - | - | 1.1 | - | - | V |
| | | $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$ | 1.3 | - | - | 1.3 | - | - | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | 1.4 | - | - | 1.4 | - | - | V |
| VIL | LOW-level | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | - | - | 0.3 | - | 0.3 | 0.3 | V |
| | input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.4 | - | 0.4 | 0.3 | V |
| | | V_{CC} = 2.3 V to 2.7 V | - | - | 0.4 | - | 0.4 | 0.4 | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | - | 0.5 | - | 0.5 | 0.5 | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | 0.6 | - | 0.6 | 0.6 | V |
| I | input leakage current | select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V | - | - | - | - | ±0.5 | ±1 | μA |
| S(OFF) | OFF-state leakage | nY0 and nY1 port; see <u>Figure 4</u> | | | | | | | |
| current | current | V_{CC} = 1.4 V to 3.6 V | - | - | ±5 | - | ±50 | ±500 | nA |
| | | V_{CC} = 3.6 V to 4.3 V | - | - | ±10 | - | ±50 | ±500 | nA |
| S(ON) | ON-state leakage current | nZ port; V _{CC} = 1.4 V to 3.6 V; see <u>Figure 5</u> | | | | | | | |
| | | V_{CC} = 1.4 V to 3.6 V | - | - | ±5 | - | ±50 | ±500 | nA |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | ±10 | - | ±50 | ±500 | nA |
| СС | supply current | $V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC} | | | | | | | |
| | | $V_{CC} = 3.6 V$ | - | - | 100 | - | 500 | 5000 | nA |
| | | $V_{CC} = 4.3 V$ | - | - | 150 | - | 800 | 6000 | nA |
| ۱ _{CC} | additional | $V_{SW} = GND \text{ or } V_{CC}$ | | | | | | | |
| | supply current | $V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$ | - | 2.0 | 4.0 | - | 7 | 7 | μA |
| | | $V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$ | - | 0.35 | 0.7 | - | 1 | 1 | μA |
| | | $V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$ | - | 7.0 | 10.0 | - | 15 | 15 | μA |
| | | V _I = 1.8 V; V _{CC} = 3.6 V | - | 2.5 | 4.0 | - | 5 | 5 | μA |
| | | V _I = 1.8 V; V _{CC} = 2.5 V | - | 50 | 200 | - | 300 | 500 | nA |
| Cı | input capacitance | | - | 1 | - | - | - | - | pF |
| C _{S(OFF)} | OFF-state | supply path switch | - | 35 | - | - | - | - | pF |
| - (- · · / | capacitance | data path switch | - | 3 | - | - | - | - | pF |
| C _{S(ON)} | ON-state | supply path switch | - | 130 | - | - | - | - | , pF |
| -(0.1) | capacitance | data path switch | - | 16 | - | - | - | - | pF |

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Low-ohmic four-pole double-throw analog switch

11.1 Test circuits





11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 12.

| Symbol | Parameter | Conditions | | –40 °C to | o +85 °C | $T_{amb} = -40$ | $T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$ | | |
|-----------------|---------------------------------|---|-----|----------------------|----------|-----------------|---|---|--|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | | |
| Supply p | oath switch | | • | | | ' | 1 | | |
| R _{ON} | ON resistance | $V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see <u>Figure 6</u> | | | | | | | |
| | | V_{CC} = 1.8 V; V_{SW} = 0 V, 1.8 V | - | 0.5 | 0.75 | - | 0.85 | Ω | |
| | | V_{CC} = 2.7 V; V_{SW} = 0 V, 2.3 V | - | 0.45 | 0.7 | - | 0.8 | Ω | |
| ΔR_{ON} | ON resistance | $V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$ [2] | | | | | | | |
| | mismatch between channels | $V_{CC} = 2.7 \text{ V}; V_{SW} = 0 \text{ V}$ | - | 0.1 | - | - | - | Ω | |

Low-ohmic four-pole double-throw analog switch

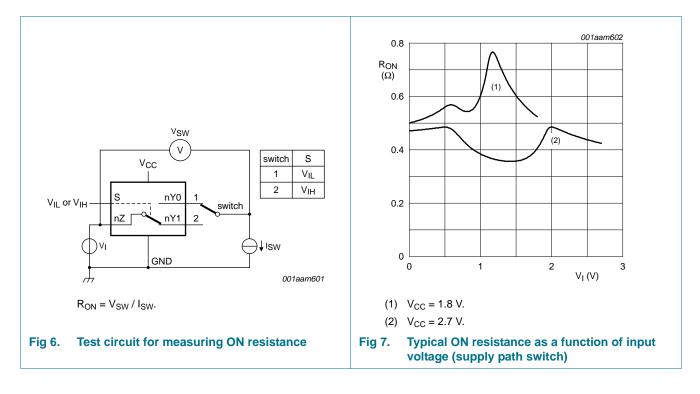
| At recom | mended operatin | g conditions; voltages are referenced | to GND | (ground | = 0 V); fo | r graphs see | Figure 7 to <u>Fig</u> | <u>ure 12</u> . | |
|-------------------|---------------------------------|--|----------------------|-----------|------------|-------------------|------------------------|-----------------|--|
| Symbol | Parameter | Conditions | T _{amb} = | -40 °C to | o +85 °C | T_{amb} = -40 ° | mb = −40 °C to +125 °C | | |
| | | Min | Typ <mark>[1]</mark> | Max | Min | Max | | | |
| Data pat | h switches | | | | | | | | |
| R _{ON} O | ON resistance | $V_I = GND$ to V_{CC} ; $I_{SW} = 20$ mA; see Figure 6 | | | | | | | |
| | | V_{CC} = 1.8 V; V_{SW} = 0 V, 1.8 V | - | 7.0 | 10.0 | - | 11.0 | Ω | |
| | | V_{CC} = 2.7 V; V_{SW} = 0 V, 2.3 V | - | 6.0 | 9.5 | - | 10.5 | Ω | |
| ΔR_{ON} | ON resistance | $V_{I} = GND \text{ to } V_{CC}; I_{SW} = 20 \text{ mA}$ [2] | | | | | | | |
| b | mismatch between channels | $V_{CC} = 2.7 \text{ V}; V_{SW} = 0 \text{ V}$ | - | 0.2 | - | - | - | Ω | |

Table 8. ON resistance ...continued

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC}, temperature and input voltage.

11.3 ON resistance test circuit and graphs



NXP Semiconductors

NX3DV2567-Q100

Low-ohmic four-pole double-throw analog switch

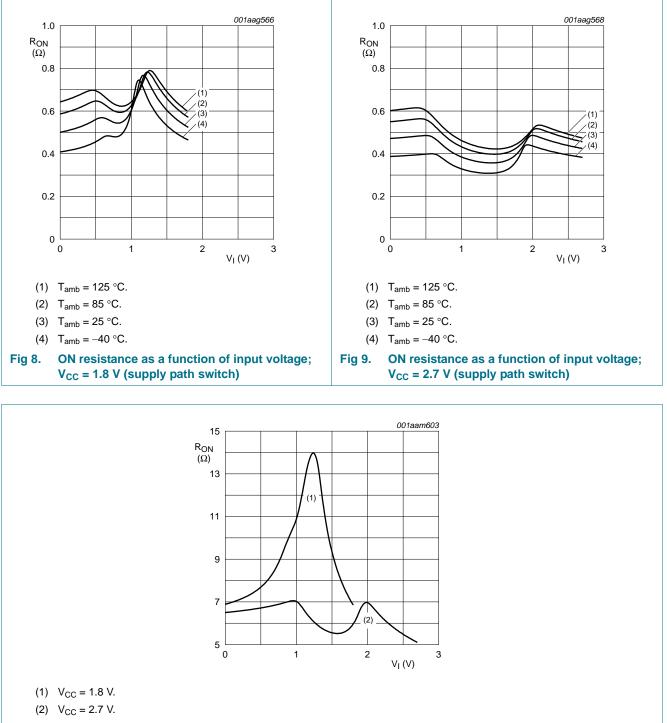
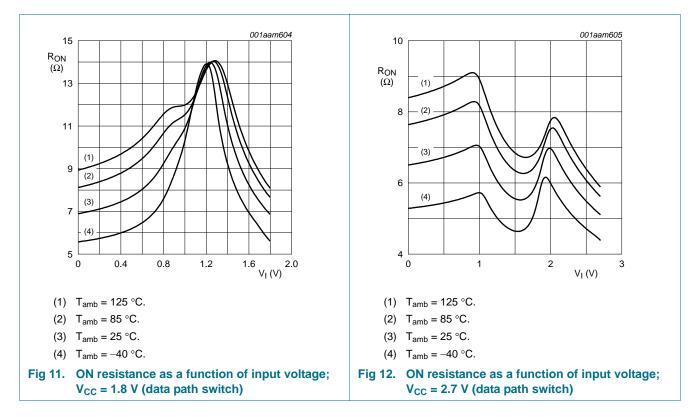


Fig 10. Typical ON resistance as a function of input voltage (data path switch)

NX3DV2567_Q100
Product data sheet

8 of 19

Low-ohmic four-pole double-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see Figure 15.

| Symbol | Parameter | Conditions | | 25 °C | _ | -40 | –40 °C to +125 °C | | | |
|------------------|--------------|--|-----|----------------------|-----|-----|-------------------|-----------------|----|--|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max (85 °C) | Max (125 °C) | | |
| Supply p | oath switch | | | | | | | | | |
| t _{en} | enable time | S to 1Z or 1Y0, 1Y1; see <u>Figure 13</u> | | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | - | 41 | 90 | - | 120 | 120 | ns | |
| | | V_{CC} = 1.65 V to 1.95 V | - | 30 | 70 | - | 80 | 90 | ns | |
| | | V_{CC} = 2.3 V to 2.7 V | - | 20 | 45 | - | 50 | 55 | ns | |
| | | V_{CC} = 2.7 V to 3.6 V | - | 19 | 40 | - | 45 | 50 | ns | |
| | | V_{CC} = 3.6 V to 4.3 V | - | 19 | 40 | - | 45 | 50 | ns | |
| t _{dis} | disable time | S to 1Z or 1Y0, 1Y1; see <u>Figure 13</u> | | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | - | 24 | 70 | - | 80 | 90 | ns | |
| | | V_{CC} = 1.65 V to 1.95 V | - | 15 | 55 | - | 60 | 65 | ns | |
| | | V_{CC} = 2.3 V to 2.7 V | - | 9 | 25 | - | 30 | 35 | ns | |
| | | V_{CC} = 2.7 V to 3.6 V | - | 8 | 20 | - | 25 | 30 | ns | |
| | | V_{CC} = 3.6 V to 4.3 V | - | 8 | 20 | - | 25 | 30 | ns | |

Low-ohmic four-pole double-throw analog switch

| Symbol | Parameter | Conditions | Conditions | | 25 °C | | -40 | °C to +12 | 5 °C | Uni |
|-----------|-------------------|--|------------|--------|-------|-----|----------------|-----------------|------|-----|
| | | | Min | Typ[1] | Мах | Min | Max (85 °C) | Max (125 °C) | | |
| b-m | break-before-make | see Figure 14 | [2] | | | | | | | |
| | time | V_{CC} = 1.4 V to 1.6 V | | - | 20 | - | 9 | - | - | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | - | 17 | - | 7 | - | - | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 13 | - | 4 | - | - | ns |
| | | V_{CC} = 2.7 V to 3.6 V | | - | 11 | - | 3 | - | - | ns |
| | | V_{CC} = 3.6 V to 4.3 V | | - | 11 | - | 2 | - | - | ns |
| Data patl | h switch | | | | | | | | | |
| en | enable time | S to nZ or nYn; see <u>Figure 13</u> | | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | | - | 40 | 90 | - | 120 | 120 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | - | 29 | 70 | - | 80 | 90 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 20 | 45 | - | 50 | 55 | ns |
| | | V_{CC} = 2.7 V to 3.6 V | | - | 19 | 40 | - | 45 | 50 | ns |
| | | $V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$ | | - | 19 | 40 | - | 45 | 50 | ns |
| dis | disable time | S to nZ or nYn; see <u>Figure 13</u> | | | | | | | | |
| | | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | | - | 21 | 70 | - | 80 | 90 | ns |
| | | $V_{CC} = 1.65 \text{ V}$ to 1.95 V | | - | 13 | 55 | - | 60 | 65 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 8 | 25 | - | 30 | 35 | ns |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | | - | 7 | 20 | - | 25 | 30 | ns |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | | - | 7 | 20 | - | 25 | 30 | ns |
| b-m | break-before-make | see Figure 14 | [2] | | | | | | | |
| | time | V_{CC} = 1.4 V to 1.6 V | | - | 23 | - | 9 | - | - | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | - | 19 | - | 7 | - | - | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 15 | - | 4 | - | - | ns |
| | | V_{CC} = 2.7 V to 3.6 V | | - | 13 | - | 3 | - | - | ns |
| | | $V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$ | | - | 12 | - | 2 | - | - | ns |

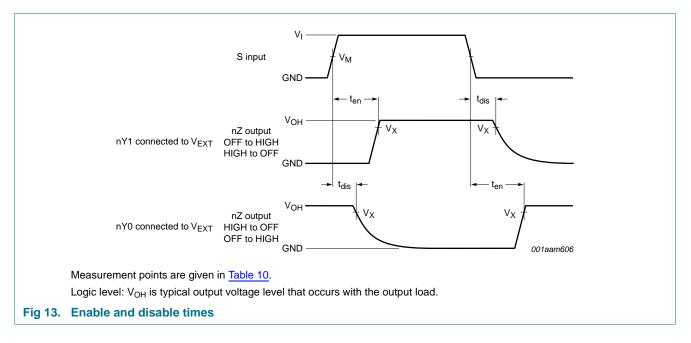
Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see Figure 15.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

Low-ohmic four-pole double-throw analog switch



12.1 Waveform and test circuits

Table 10. Measurement points

| Supply voltage | Input | Output |
|-----------------|--------------------|--------------------|
| V _{cc} | V _M | V _X |
| 1.4 V to 4.3 V | 0.5V _{CC} | 0.9V _{OH} |

Low-ohmic four-pole double-throw analog switch

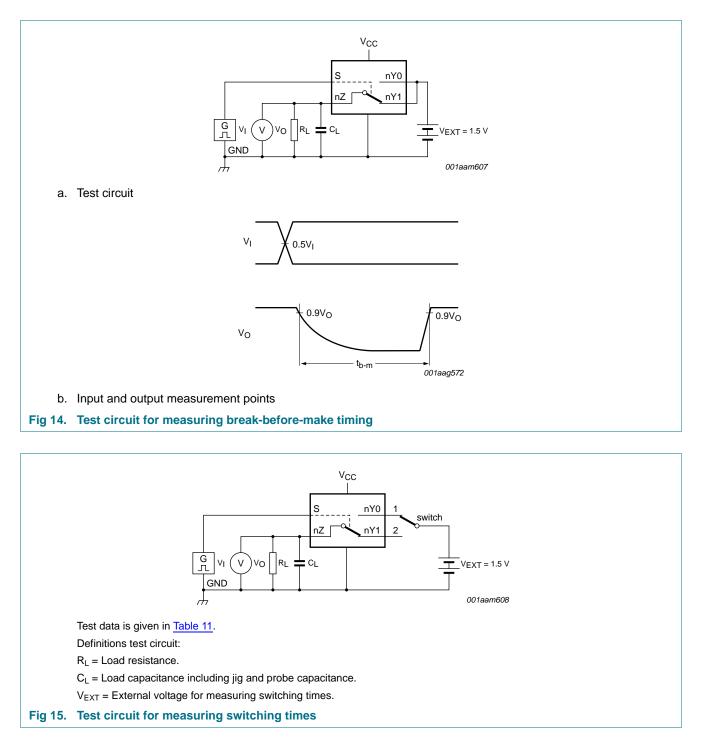


Table 11. Test data

| Supply voltage | Input | | e Input Load | | |
|-----------------|-----------------|---------------------------------|--------------|------|--|
| V _{cc} | VI | t _r , t _f | CL | RL | |
| 1.4 V to 4.3 V | V _{CC} | \leq 2.5 ns | 35 pF | 50 Ω | |

Low-ohmic four-pole double-throw analog switch

12.2 Additional dynamic characteristics

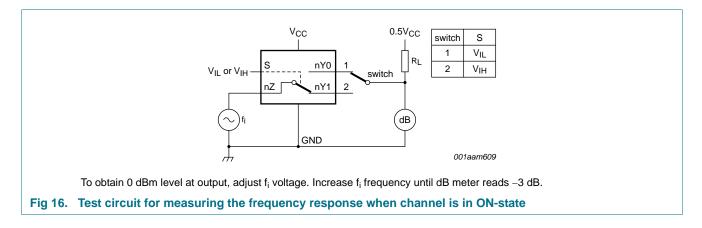
Table 12. Additional dynamic characteristics

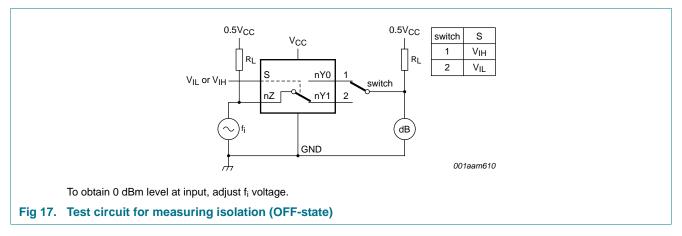
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

| Symbol | Parameter | Conditions | Mir | า Тур | Max | Unit |
|-----------------------|-----------------------------|---|-----|-------|-----|------|
| Data pat | h switch | | | | | |
| f _(-3dB) | –3 dB frequency response | $R_L = 50 \Omega$; see Figure 16 | [1] | | | |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | | - 330 | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 10 \text{ MHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 17}}{10000000000000000000000000000000000$ | [1] | | | |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | | -60 | - | dB |
| Xtalk crosstal | crosstalk | between switches; $f_i = 10 \text{ MHz}$; $R_L = 50 \Omega$; see <u>Figure 18</u> | [1] | | | |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | | -60 | - | dB |
| Q _{inj} | charge injection | $f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 19}}{10000000000000000000000000000000000$ | | | | |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | • | - 10 | - | рС |

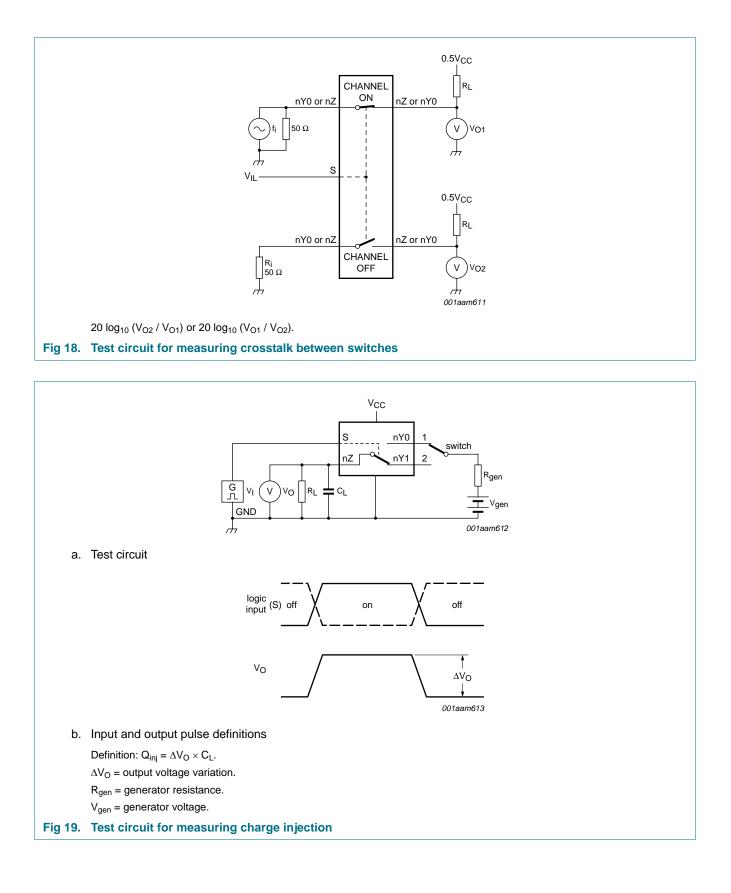
[1] f_i is biased at 0.5V_{CC}.

12.3 Test circuits





Low-ohmic four-pole double-throw analog switch



NX3DV2567_Q100 Product data sheet

NXP Semiconductors

NX3DV2567-Q100

Low-ohmic four-pole double-throw analog switch

13. Package outline

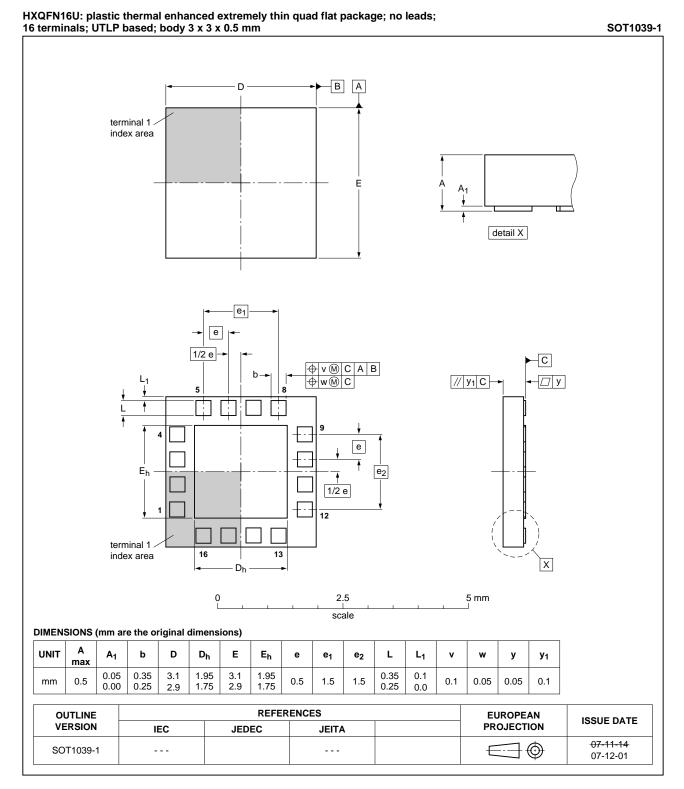


Fig 20. Package outline SOT1039-1 (HXQFN16U)

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Product data sheet

Low-ohmic four-pole double-throw analog switch

14. Abbreviations

| Table 13. | Abbreviations | | |
|-----------|---|--|--|
| Acronym | Description | | |
| CDM | Charged Device Model | | |
| CMOS | Complementary Metal-Oxide Semiconductor | | |
| ESD | ElectroStatic Discharge | | |
| HBM | Human Body Model | | |
| MM | Machine Model | | |
| PDA | Personal Digital Assistant | | |
| TTL | Transistor-Transistor Logic | | |

15. Revision history

| Table 14. Revision his | Revision history | | | |
|------------------------|------------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| NX3DV2567_Q100 v.1 | 20140120 | Product data sheet | - | - |

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16. Legal information

16.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
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18. Contents

| 1 | General description | 1 |
|------|---------------------------------------|----|
| 2 | Features and benefits | 1 |
| 3 | Applications | 2 |
| 4 | Ordering information | 2 |
| 5 | Marking | 2 |
| 6 | Functional diagram | 2 |
| 7 | Pinning information | 3 |
| 7.1 | Pinning | 3 |
| 7.2 | Pin description | 3 |
| 8 | Functional description | 3 |
| 9 | Limiting values | 4 |
| 10 | Recommended operating conditions | 4 |
| 11 | Static characteristics | 5 |
| 11.1 | Test circuits | 6 |
| 11.2 | ON resistance | 6 |
| 11.3 | ON resistance test circuit and graphs | 7 |
| 12 | Dynamic characteristics | 9 |
| 12.1 | | 11 |
| 12.2 | | 13 |
| 12.3 | | 13 |
| 13 | Package outline | 15 |
| 14 | Abbreviations | 16 |
| 15 | Revision history | 16 |
| 16 | Legal information | 17 |
| 16.1 | | 17 |
| 16.2 | Definitions | 17 |
| 16.3 | Disclaimers | 17 |
| 16.4 | Trademarks | 18 |
| 17 | Contact information | 18 |
| 18 | Contents | 19 |

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